

Chip Termination 125 Watts, 50Ω



Features:

- RoHS Compliant
- 125 Watts
- DC 4.0 GHz
- AIN Ceramic
- Non Nichrome Resistive Element
- Low VSWR
- 100% Tested

Description:

The A125N50X4 is high performance Aluminum Nitride (AIN) Chip termination intended as a low cost alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for termination circulators and for use in power combiners. The termination is also RoHS compliant!

General Specifications:

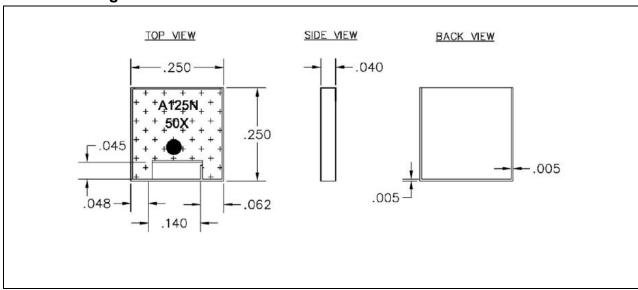
| Resistive Element | Thick Film |
|-----------------------|-------------------------------------|
| Substrate | AIN Ceramic |
| Terminal Finish | Matte Tin over Nickel Barrier |
| Operating Temperature | -50 to +150°C (see de rating chart) |

Electrical Specifications:

Resistance Value: 50 Ohms, ± 2%
Power: 125 Watts
Frequency Range: DC-4.0 GHz
Return Loss > 26 dB to 1.3 GHz
> 22 dB to 4.0GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

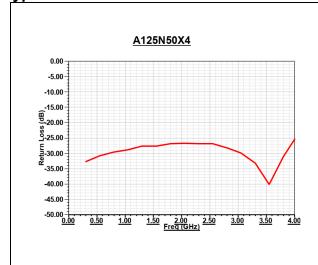
Outline Drawing:

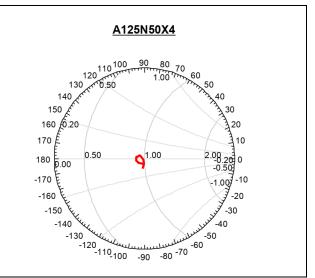


 $\overline{\text{Tolerance}}$ is ± 0.010 ", unless otherwise specified. Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions in inches.

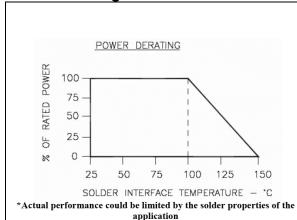


Typical Performance:

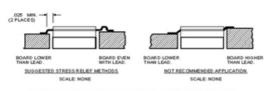




Power De-rating:



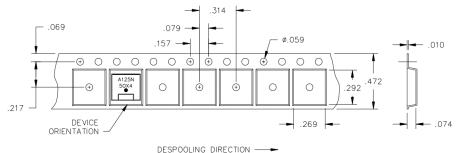
Mounting Footprint:



SUGGESTED MOUNTING PROCEDURE

- MAKE SURE THAT THE DEVICES ARE MOUNTED ON FLAT SURFACES (.001" UNDER THE DEVICE) TO OPTIMIZE THE HEAT TRANSFER.
- POSITION DEVICE ON MOUNTING SURFACE AND SOLDER IN PLACE USING AN APPROPRIATE SOLDER.
- SOLDER LEADS IN PLACE USING AN APPROPRIATE SOLDER TYPE WITH A CONTROLLED TEMPERATURE IRON.

Tape & Reel:



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